



30-P2126PA050SC-L287F09Y

datasheet

Vincotech

flow PACK 2		1200 V / 50 A
Features		flow 2 17 mm housing
	<ul style="list-style-type: none">IGBT4 (1200 V) technology for low saturation losses and improved EMC behaviorCompact and low inductive designIntegrated temperature sensor	
Target applications		Schematic
	<ul style="list-style-type: none">Industrial drives	
Types		
	<ul style="list-style-type: none">30-P2126PA050SC-L287F09Y	

Maximum Ratings

 $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	65	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	150	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	185	W
Gate-emitter voltage	V_{GES}		± 20	V
Short circuit ratings	t_{SC} V_{CC}	$T_j \leq 150^\circ\text{C}$ $V_{GE} = 15\text{ V}$	10 800	μs V
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Diode				
Peak Repetitive Reverse Voltage	V_{RRM}		1200	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	65	A
Repetitive peak forward current	I_{FRM}		100	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	127	W
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage	$t_p = 2 \text{ s}$	4000	V
Creepage distance				min. 12,7	mm
Clearance				min. 12,7	mm
Comparative Tracking Index	CTI			> 200	



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0017	25 125	5,3	5,8	6,3	V
Collector-emitter saturation voltage	V_{CEsat}		15		50	25 150	1,58	1,88 2,30	2,07	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			1	µA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	r_g							4		Ω
Input capacitance	C_{ies}	$f = 1 \text{ MHz}$						2800		
Reverse transfer capacitance	C_{res}		0	25		25		100		pF

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4 \text{ W/mK}$						0,51		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{goff} = 8 \Omega$ $R_{gon} = 8 \Omega$	± 15	600	50	25 150		96 101		ns
Rise time	t_r					25 150		17 24		
Turn-off delay time	$t_{d(off)}$					25 150		214 281		
Fall time	t_f					25 150		87 122		
Turn-on energy (per pulse)	E_{on}					25 150		2,701 4,211		
Turn-off energy (per pulse)	E_{off}					25 150		2,744 4,531		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Diode

Static

Forward voltage	V_F				50	25 125 150		1,73 1,70 1,68	2,05	V
Reverse leakage current	I_r			1200		25			10	µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4 \text{ W/mK}$						0,75		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 3866 \text{ A/µs}$ $di/dt = 2820 \text{ A/µs}$	± 15	600	50	25 150		81 85		A
Reverse recovery time	t_{rr}					25 150		139 316		ns
Recovered charge	Q_r					25 150		4,797 9,708		µC
Reverse recovered energy	E_{rec}					25 150		1,790 3,972		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 150		4803 1209		A/µs

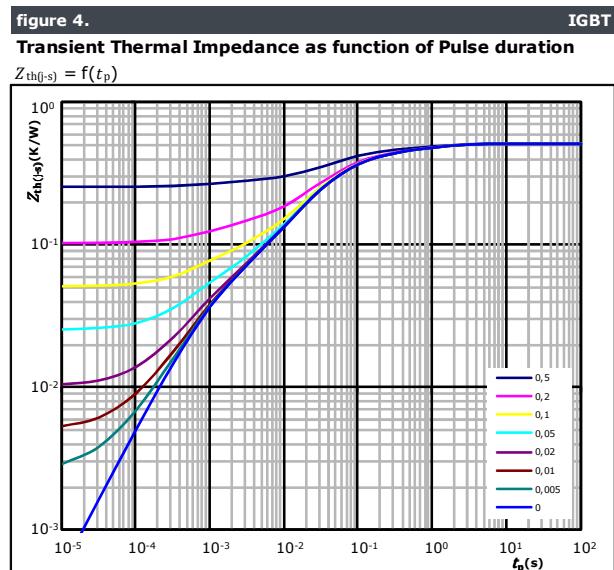
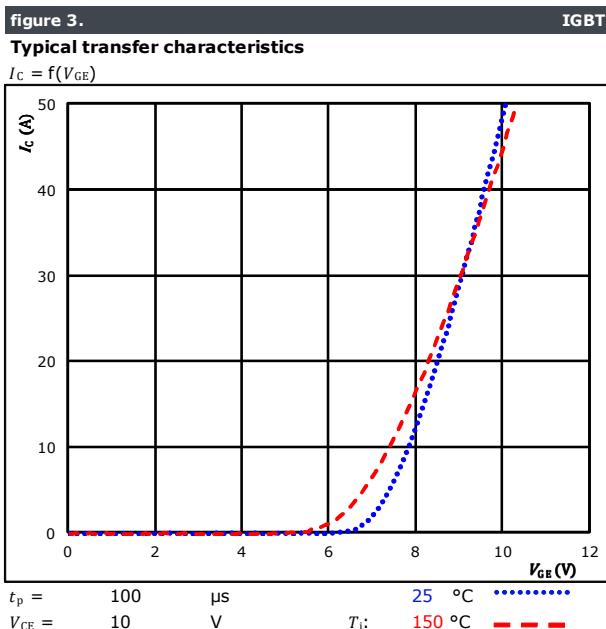
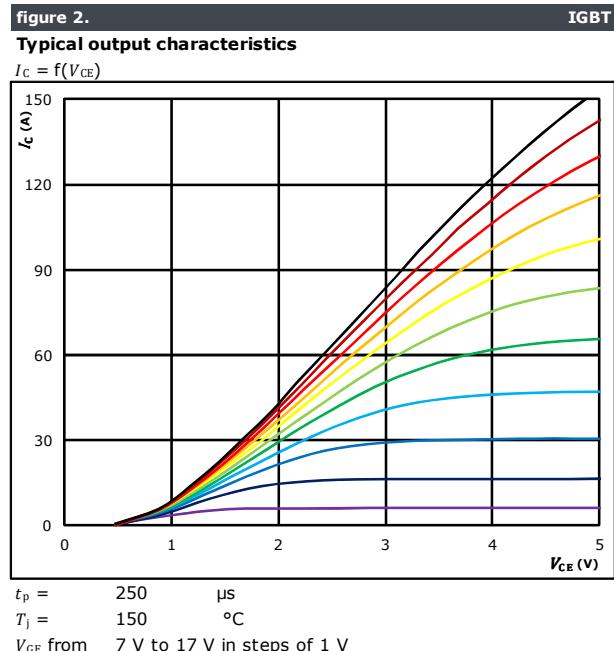
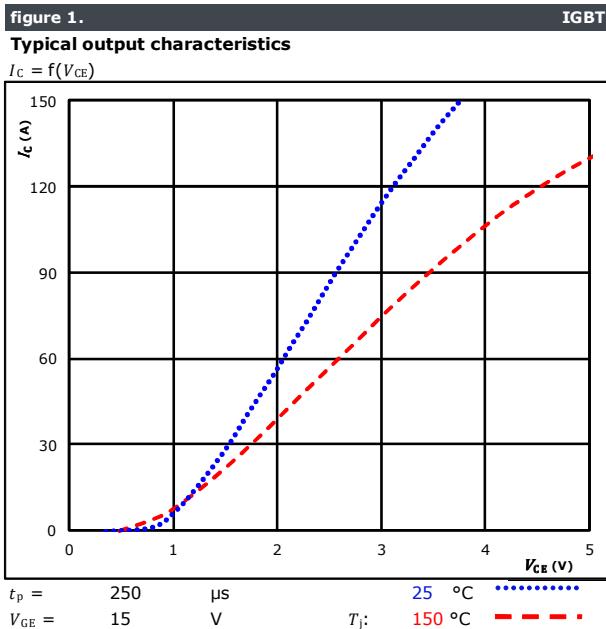
Thermistor

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1486 \Omega$				100	-12		+14	%
Power dissipation	P					25		200		mW
Power dissipation constant						25		2		mW/K
B-value	$B_{(25/50)}$	Tol. ±3%				25		3950		K
B-value	$B_{(25/100)}$	Tol. ±3%				25		3998		K
Vincotech NTC Reference									B	



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Inverter Switch Characteristics

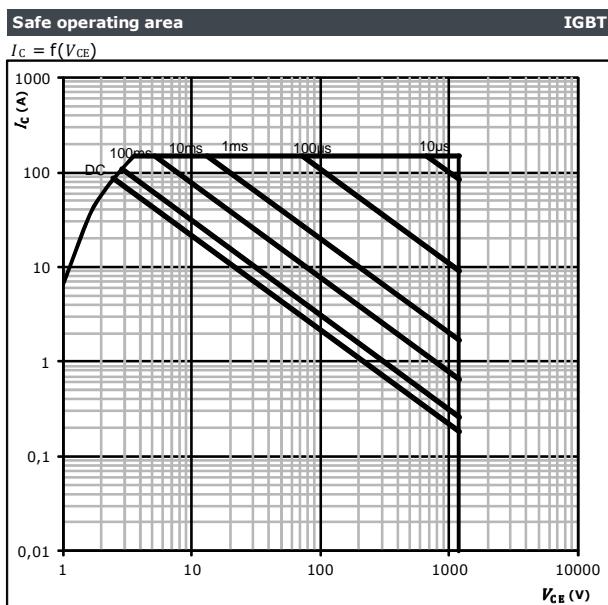


IGBT thermal model values	
R (K/W)	τ (s)
7,12E-02	1,13E+00
1,15E-01	1,65E-01
2,22E-01	3,78E-02
6,59E-02	1,21E-02
3,86E-02	9,52E-04



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Inverter Switch Characteristics



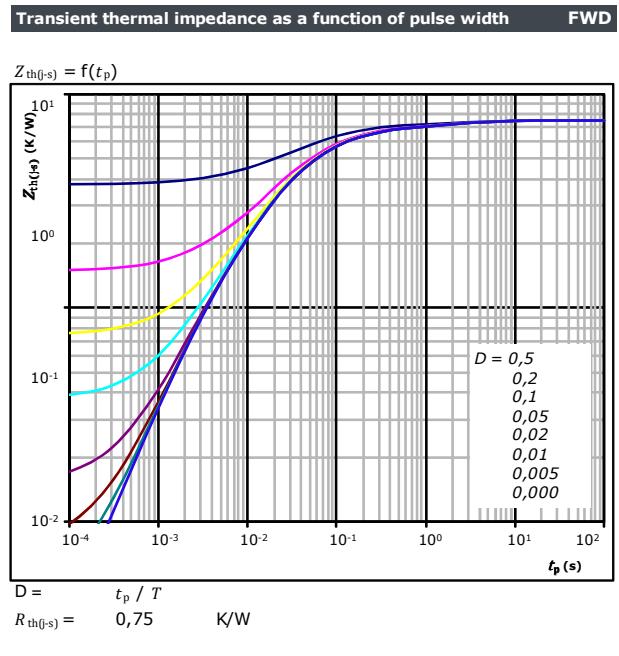
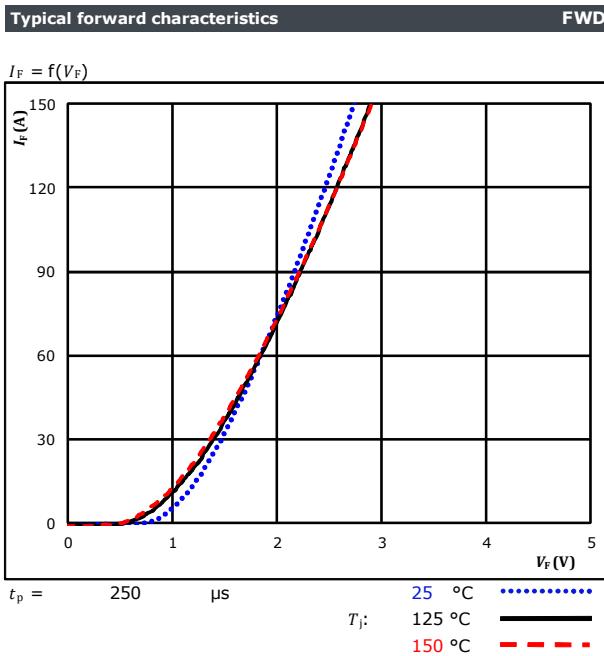
At

D = single pulse
 T_s = 80 °C
 V_{GE} = ±15 V
 T_j = T_{jmax}



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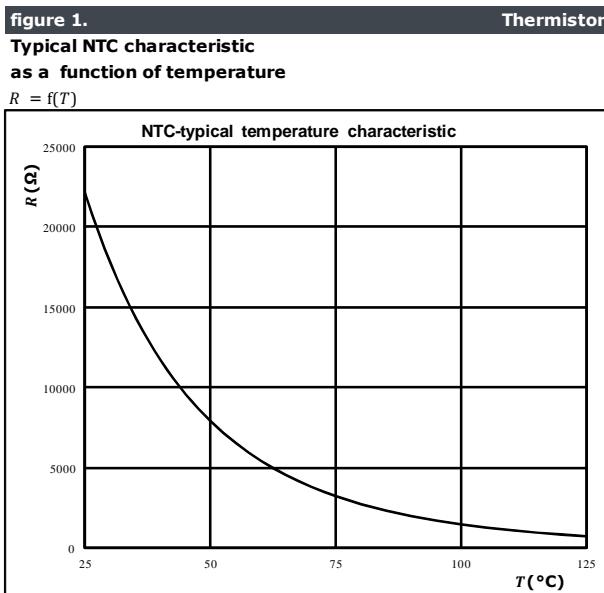
Inverter Diode Characteristics



FWD thermal model values

R (K/W)	τ (s)
4,26E-02	3,64E+00
6,76E-02	6,18E-01
2,53E-01	8,65E-02
3,23E-01	2,11E-02
6,24E-02	3,47E-03

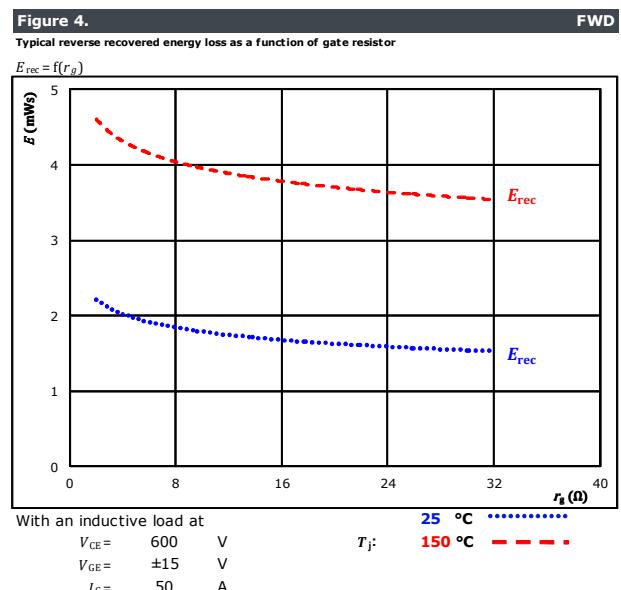
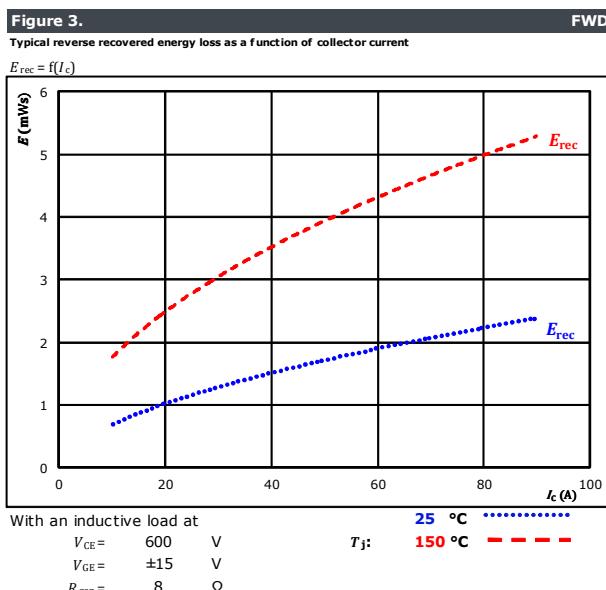
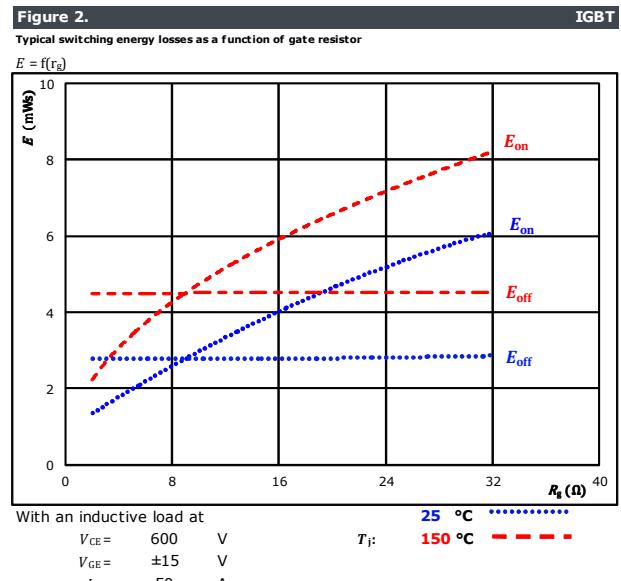
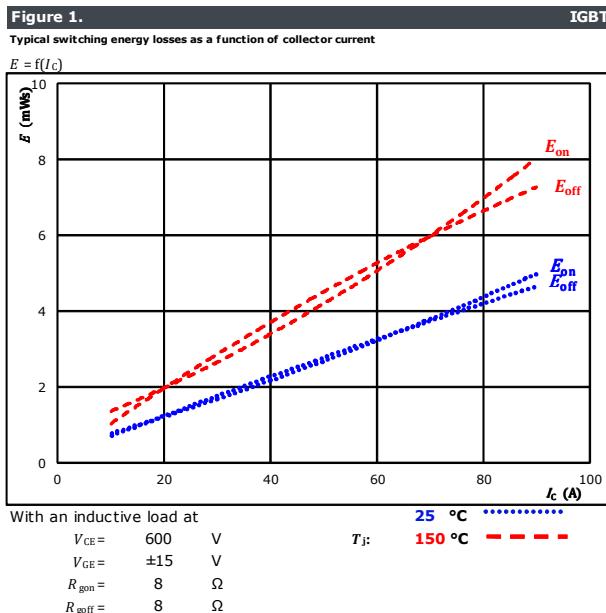
Thermistor Characteristics





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Inverter Switching Characteristics



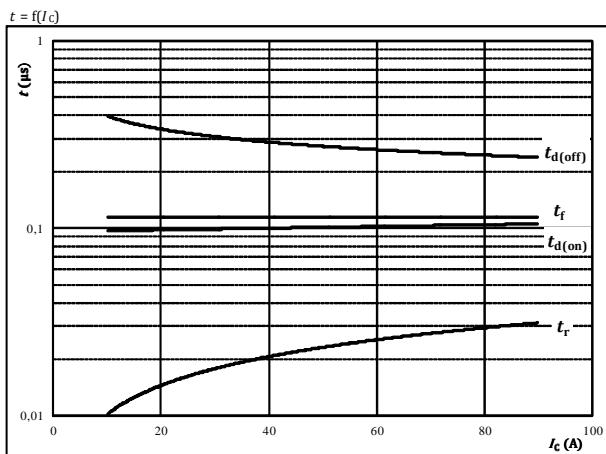


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Inverter Switching Characteristics

Figure 5. IGBT

Typical switching times as a function of collector current

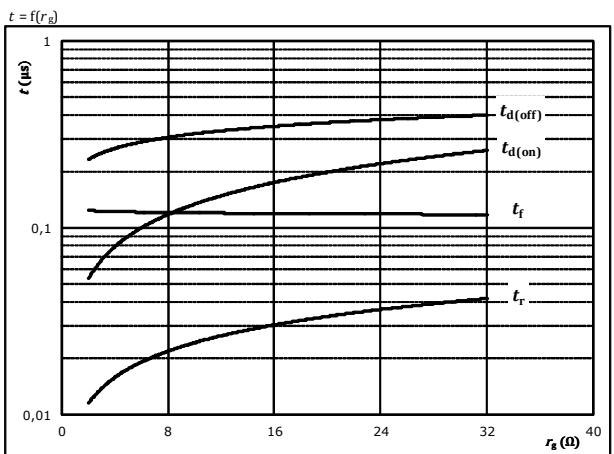


With an inductive load at

$T_J =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$R_{gon} =$	8	Ω
$R_{goff} =$	8	Ω

Figure 6. IGBT

Typical switching times as a function of gate resistor

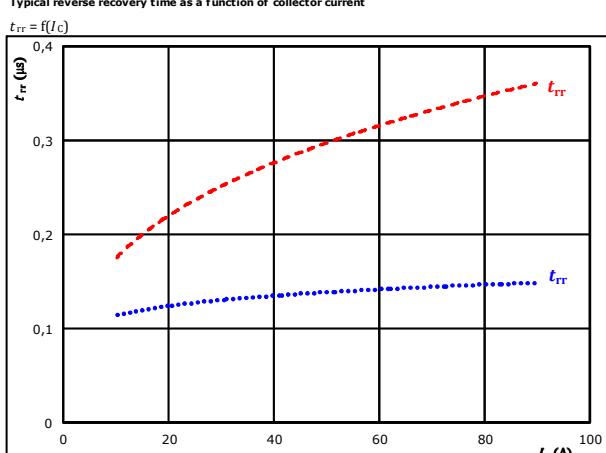


With an inductive load at

$T_J =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$I_C =$	50	A

Figure 7. FWD

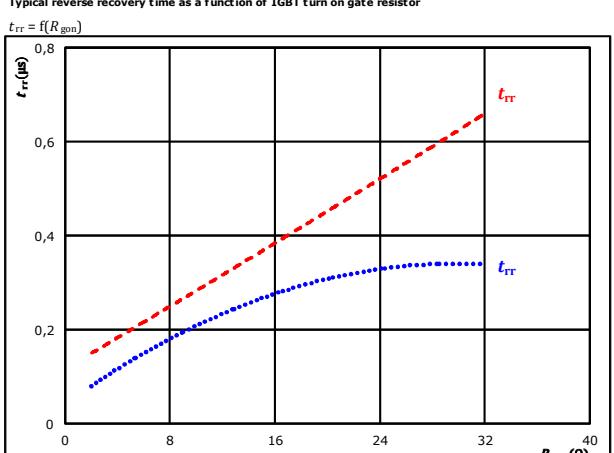
Typical reverse recovery time as a function of collector current



At	$V_{CE} =$	600	V	25 °C
	$V_{GE} =$	±15	V	$T_J:$	150 °C - - -
	$R_{gon} =$	8	Ω		

Figure 8. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

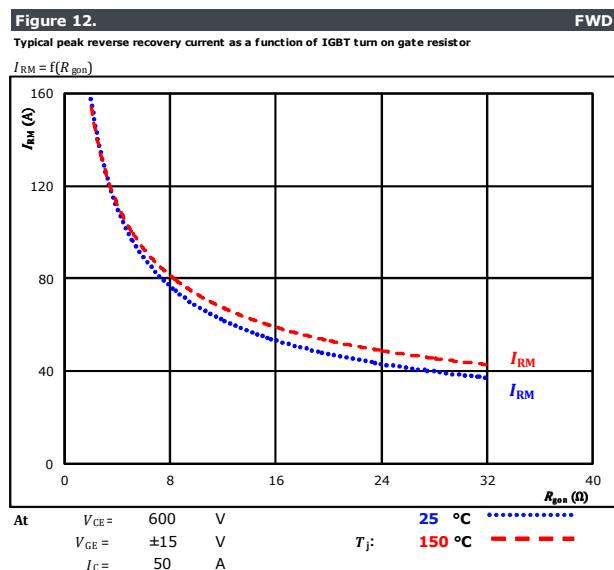
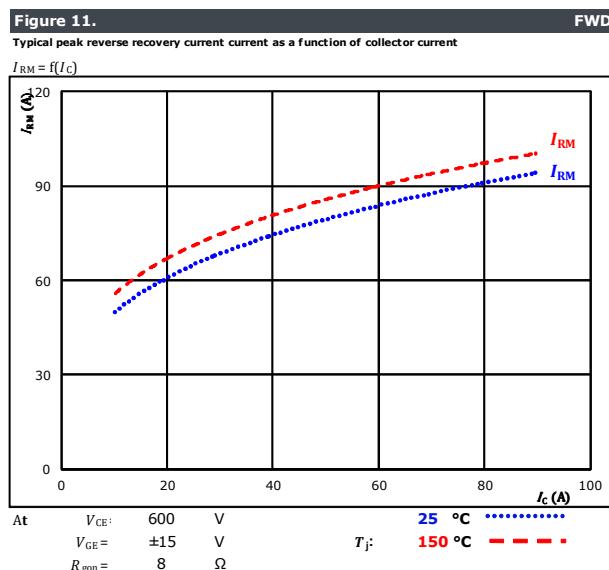
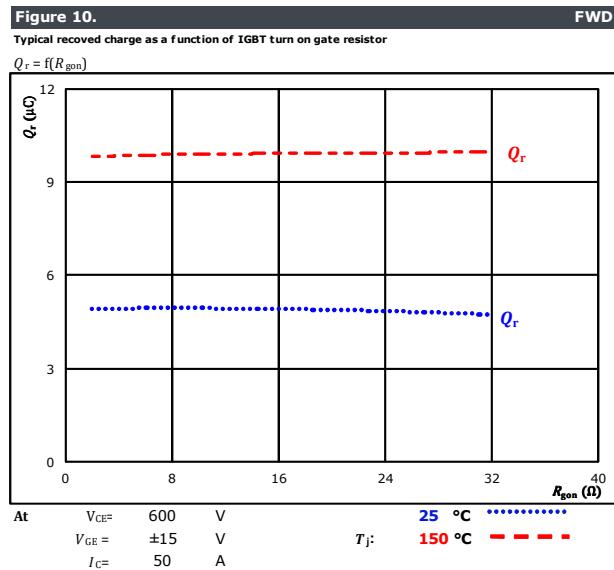
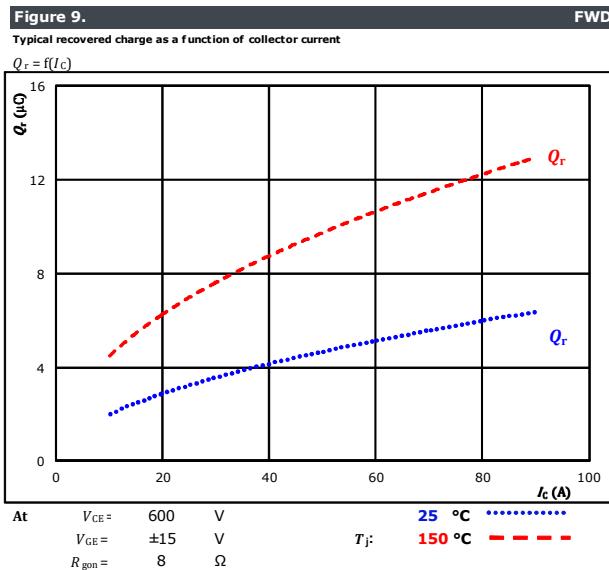


At	$V_{CE} =$	600	V	25 °C
	$V_{GE} =$	±15	V	$T_J:$	150 °C - - -
	$I_C =$	50	A		



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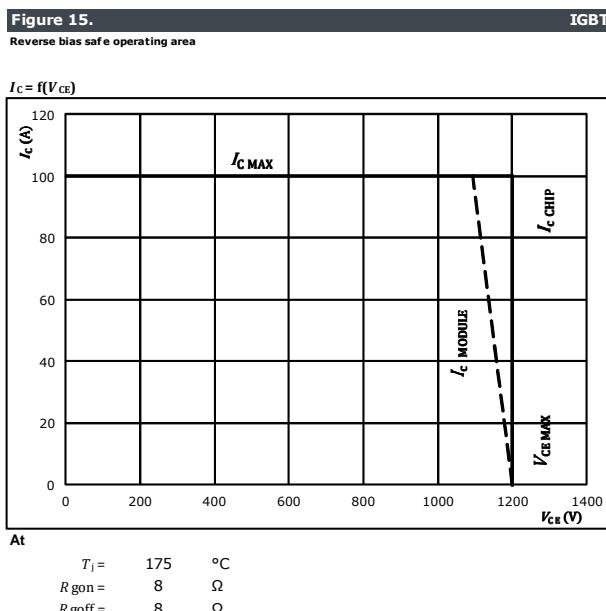
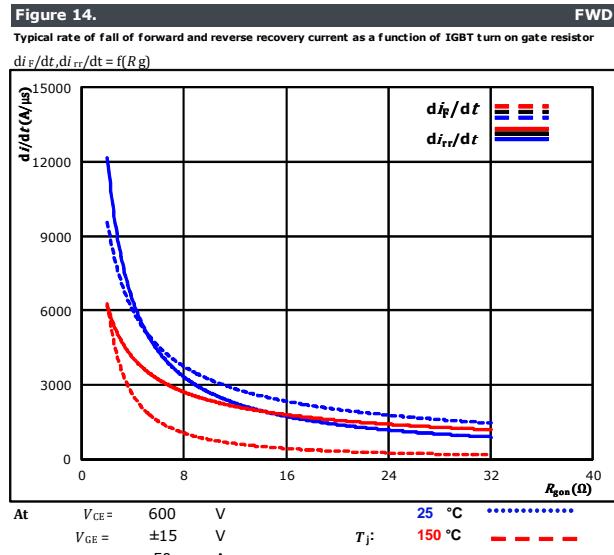
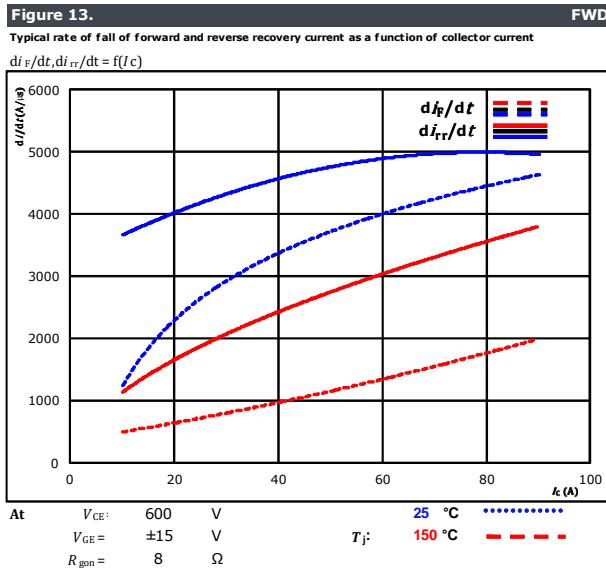
Inverter Switching Characteristics





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Inverter Switching Characteristics





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Inverter Switching Characteristics

General conditions

T_j	=	150 °C
R_{gon}	=	8 Ω
R_{goff}	=	8 Ω

Figure 1.

IGBT

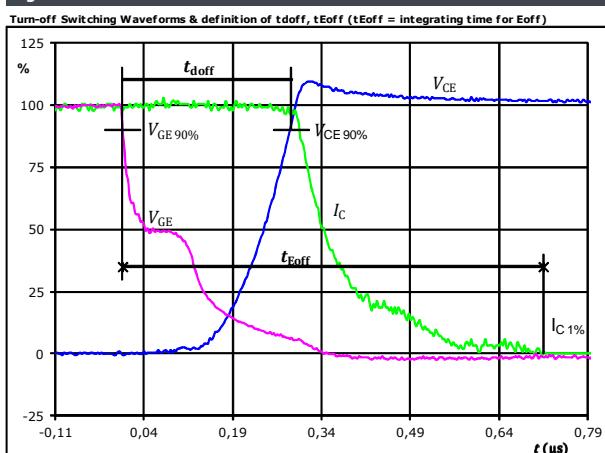


Figure 3.

IGBT

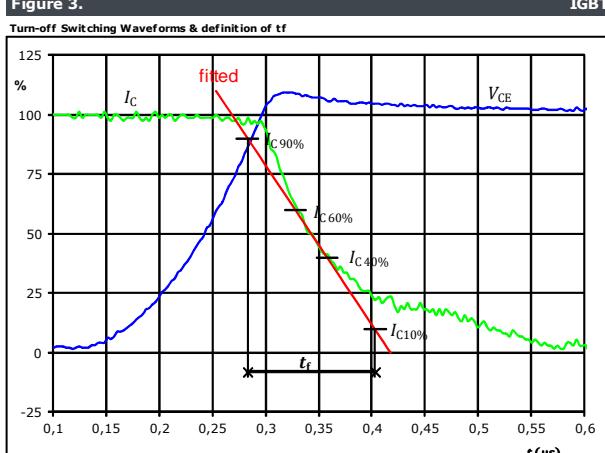


Figure 2.

IGBT

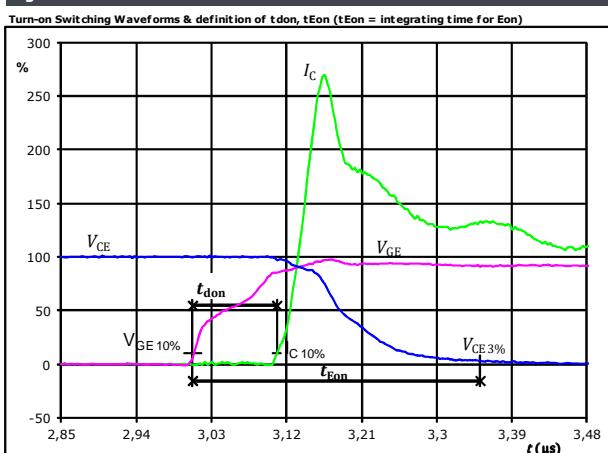
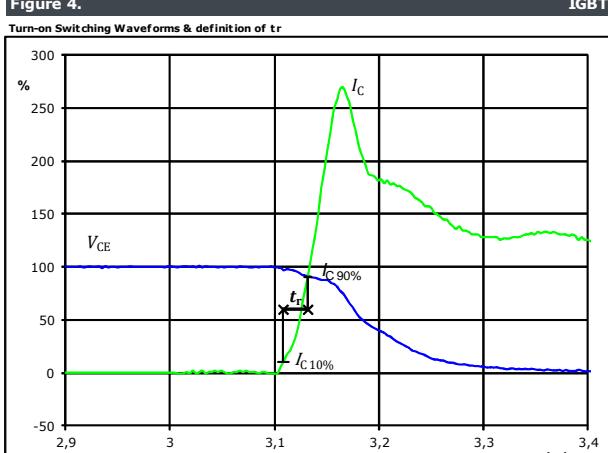


Figure 4.

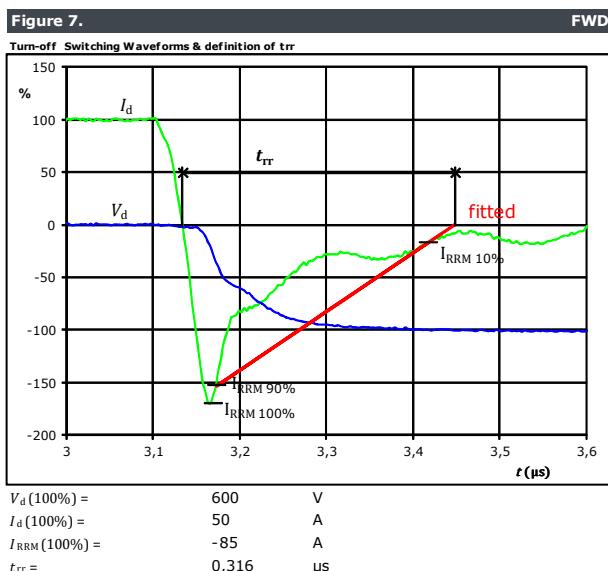
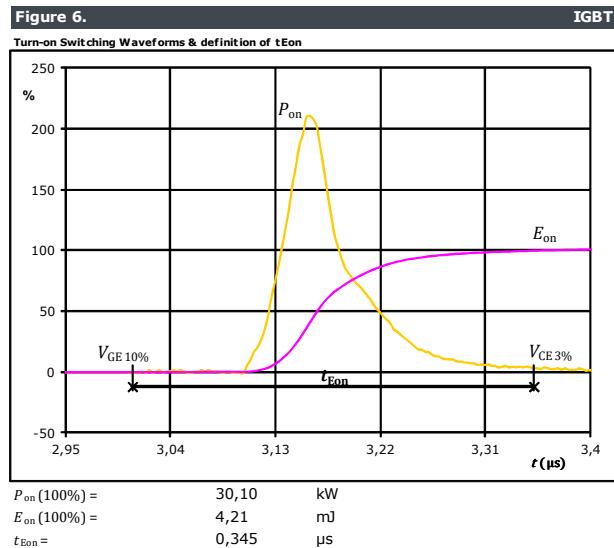
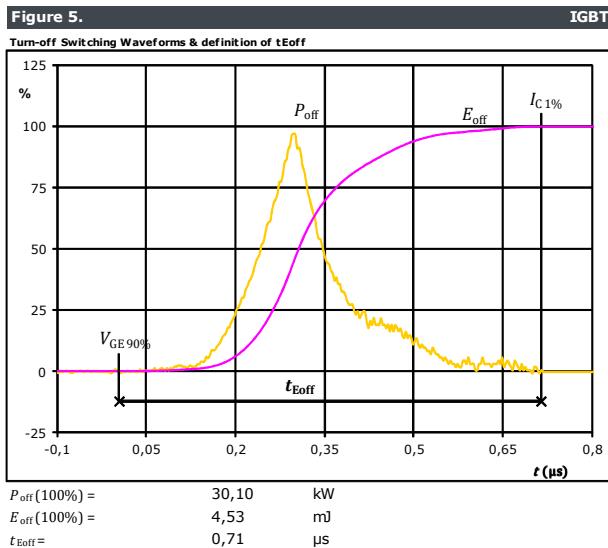
IGBT





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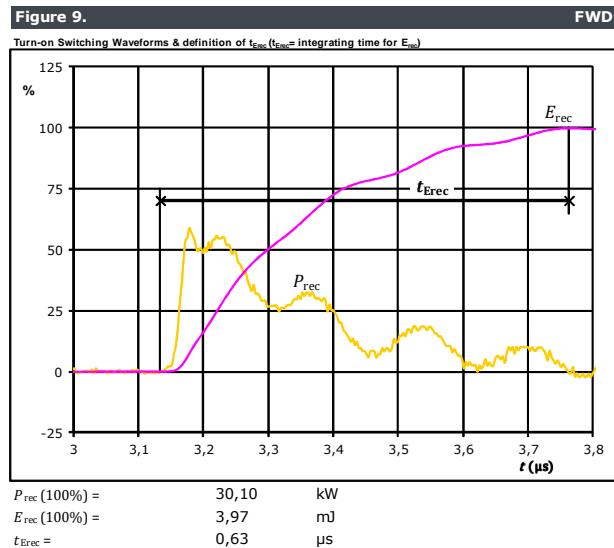
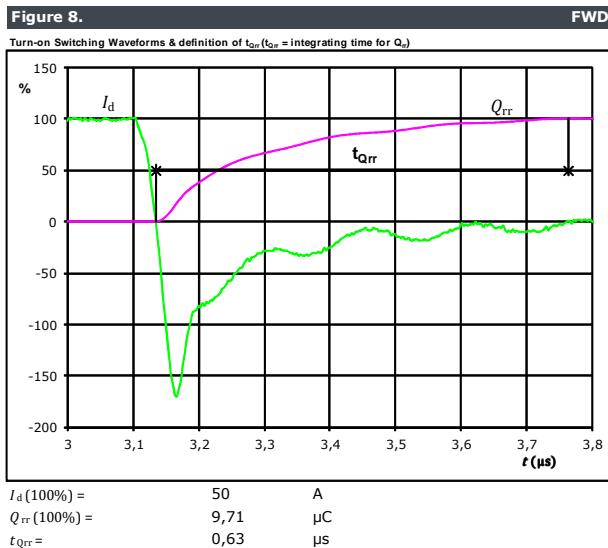
Inverter Switching Characteristics





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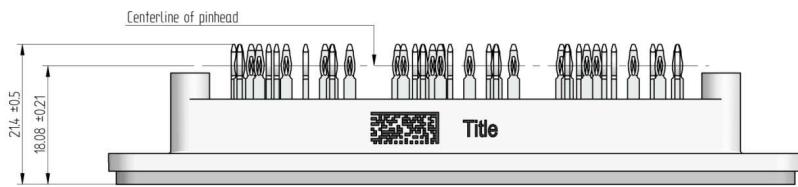
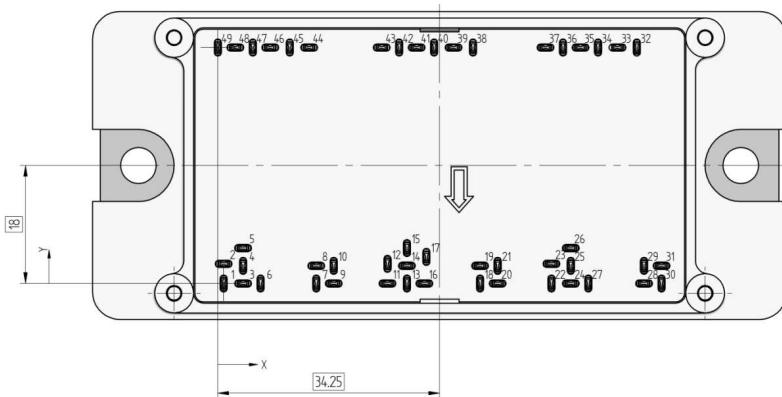
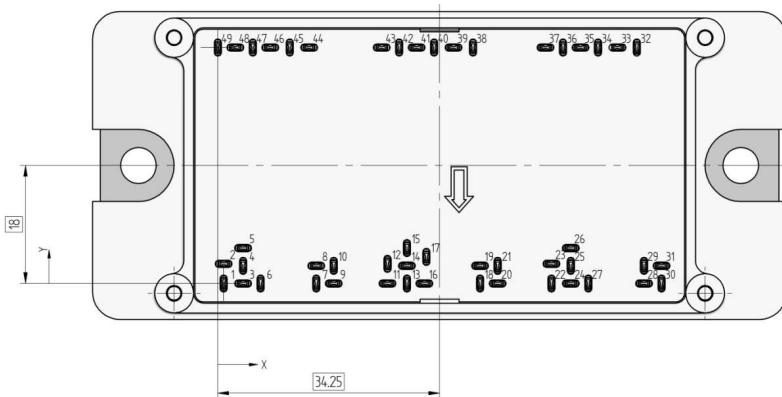
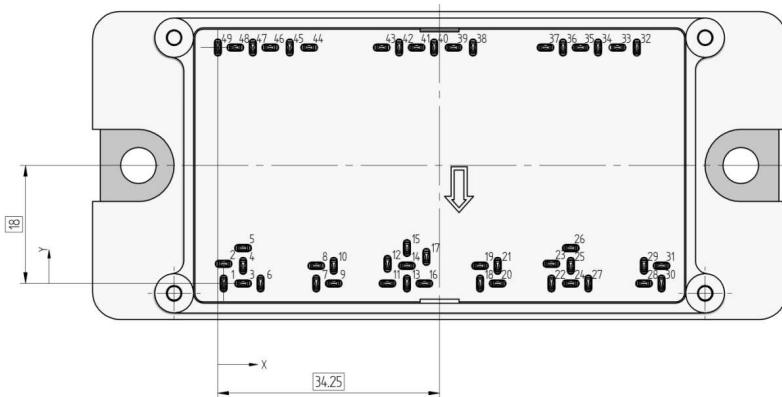
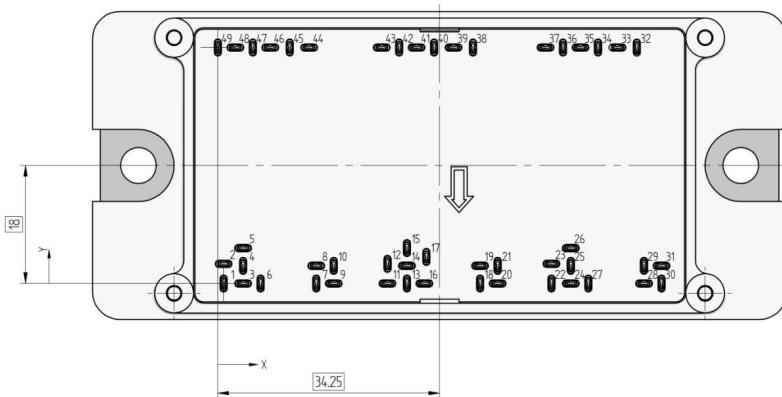
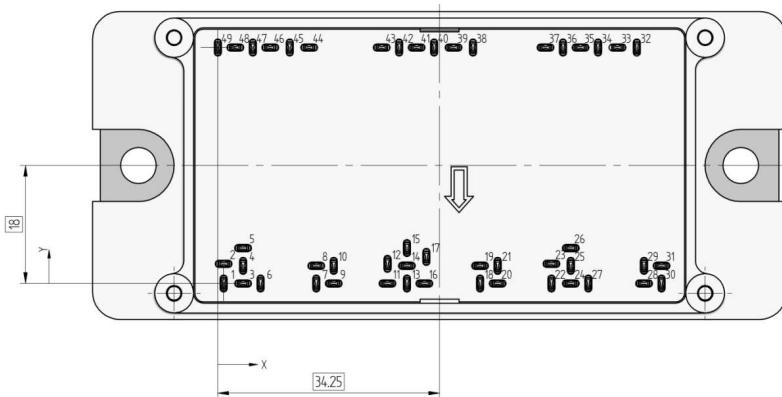
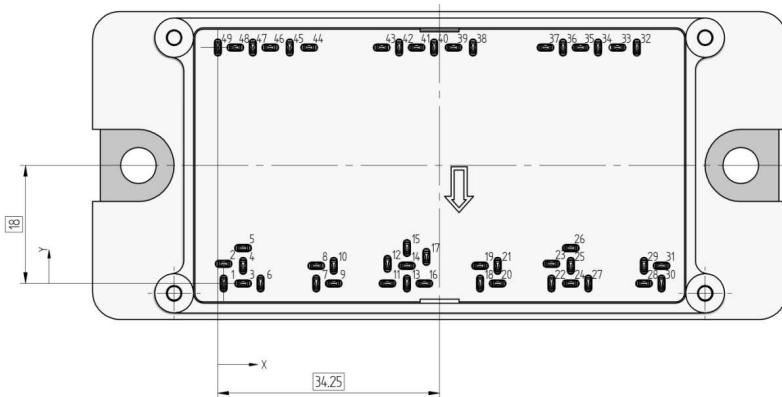
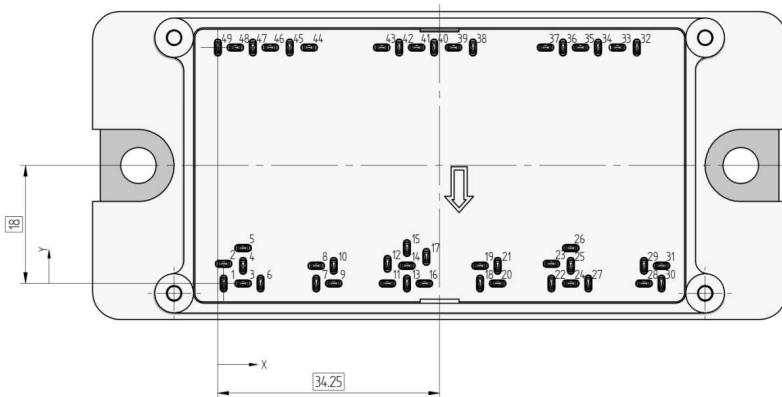
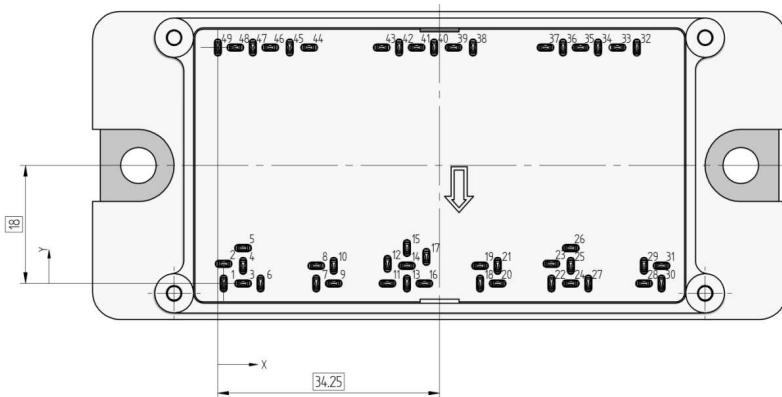
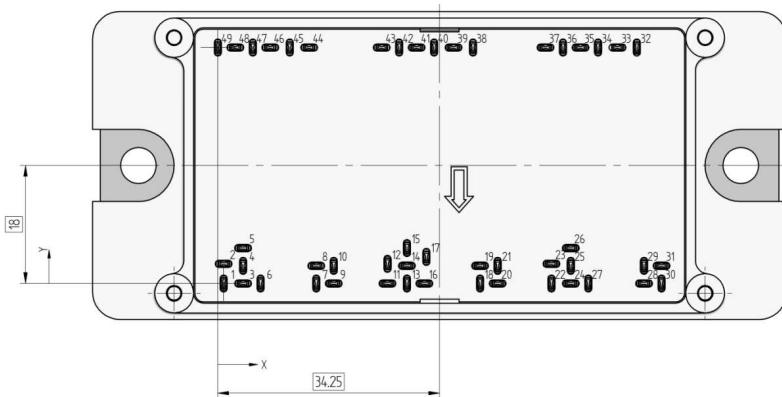
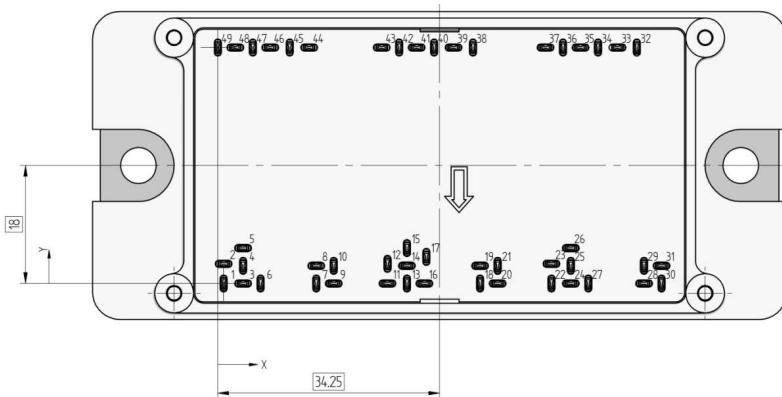
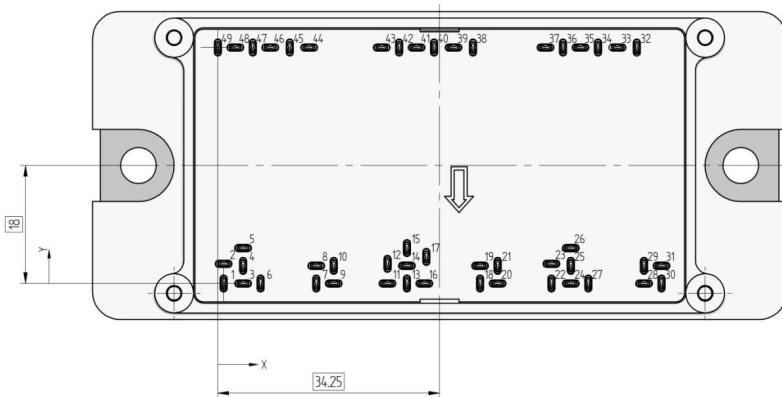
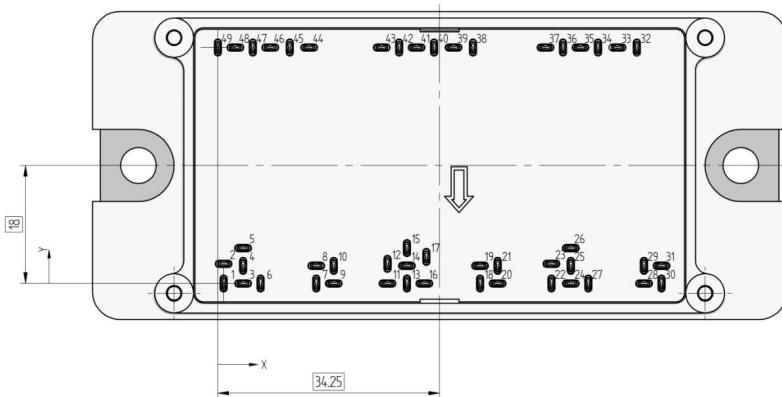
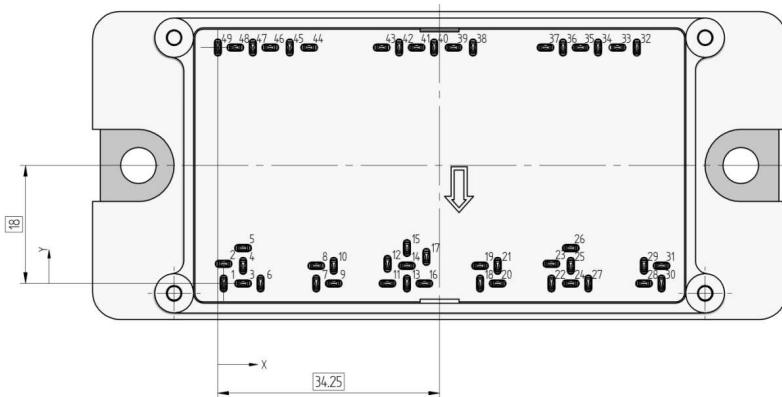
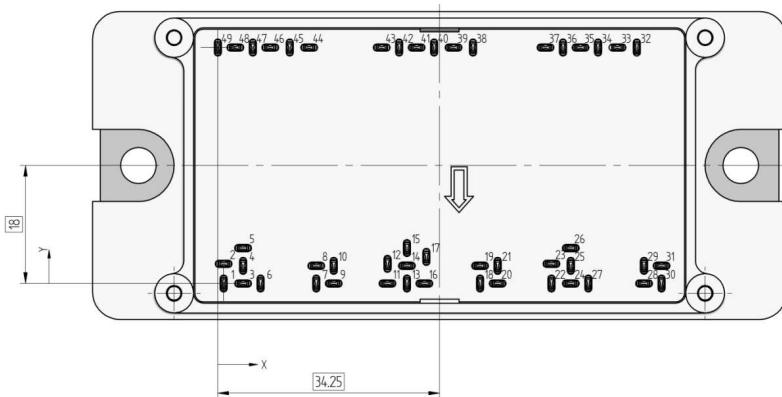
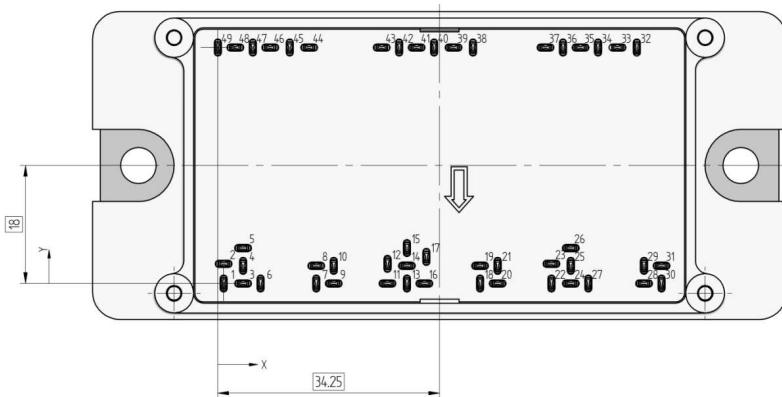
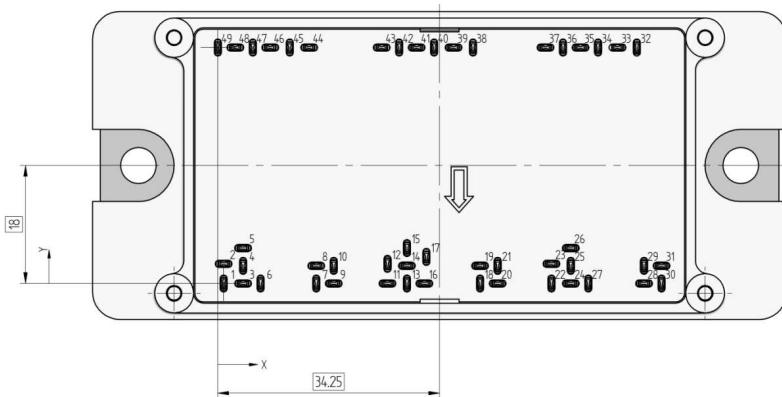
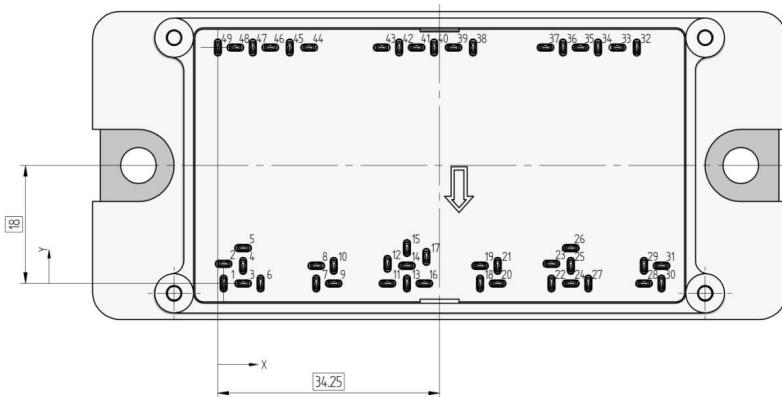
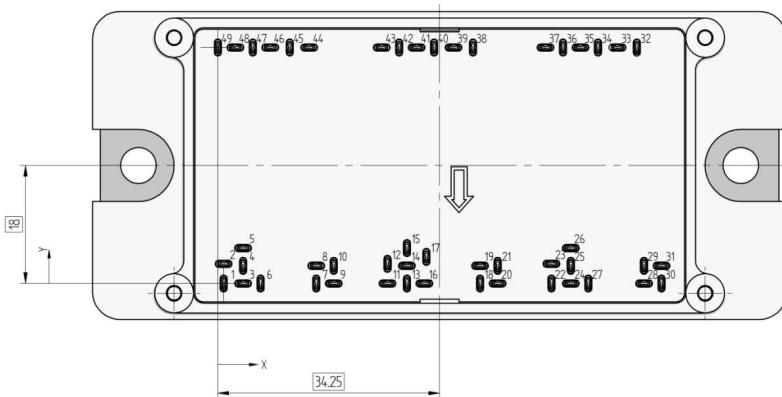
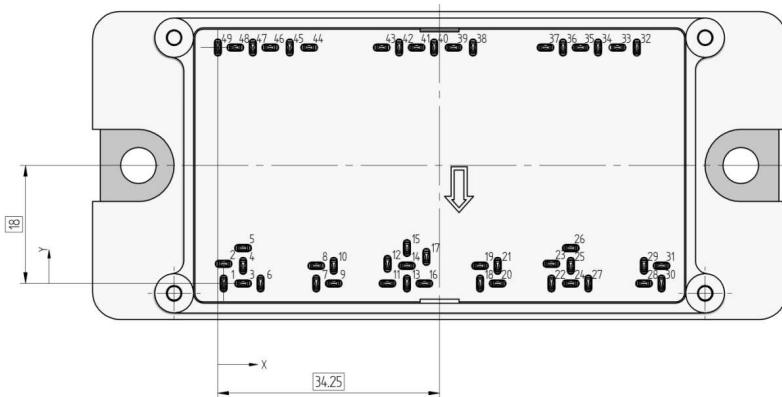
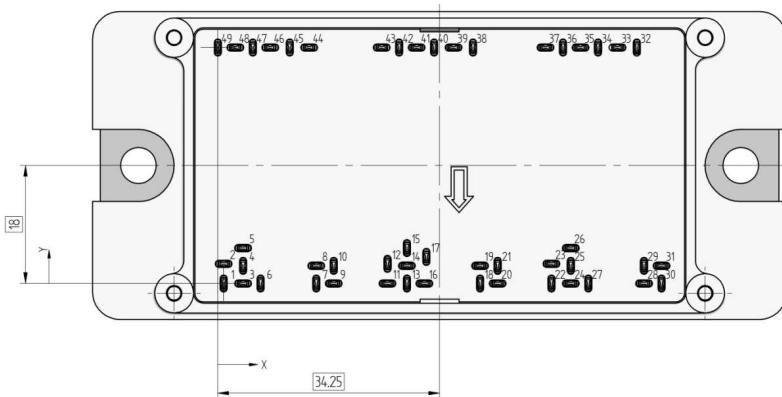
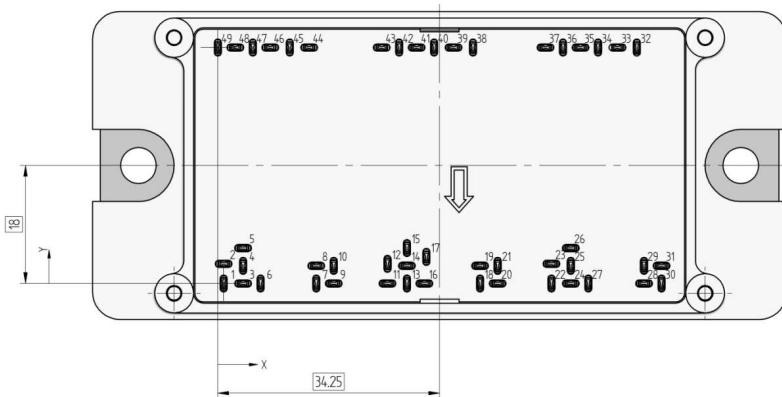
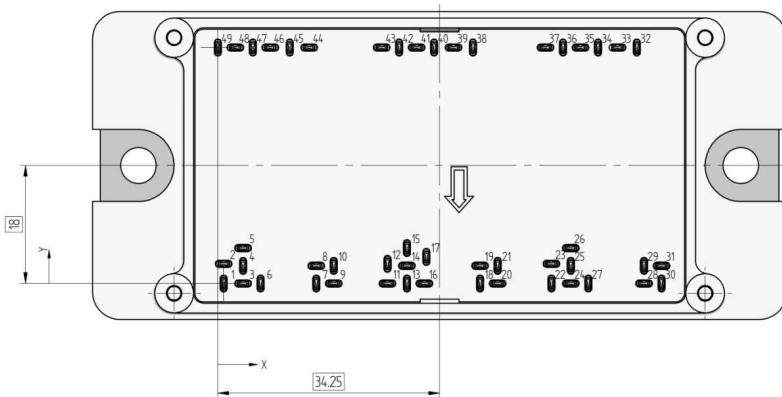
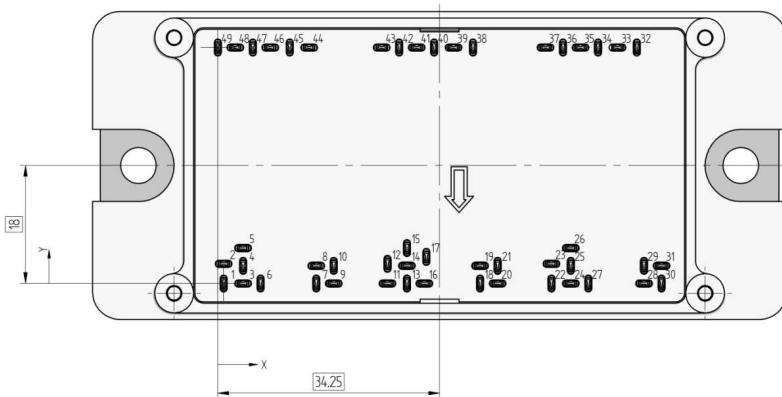
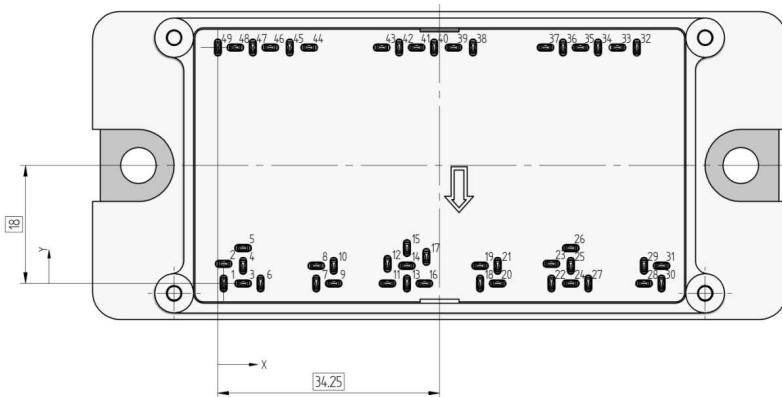
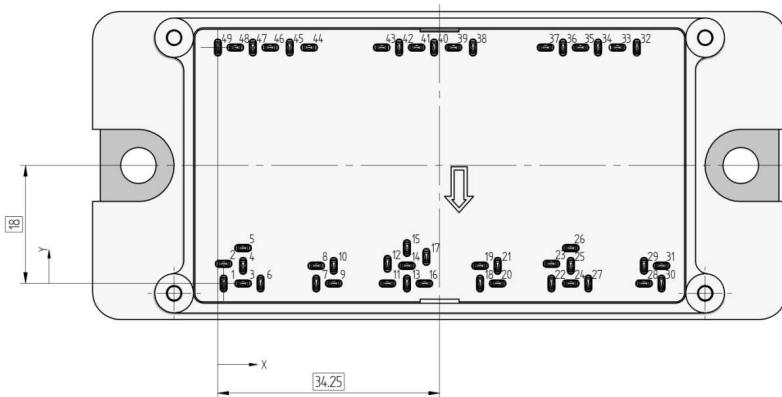
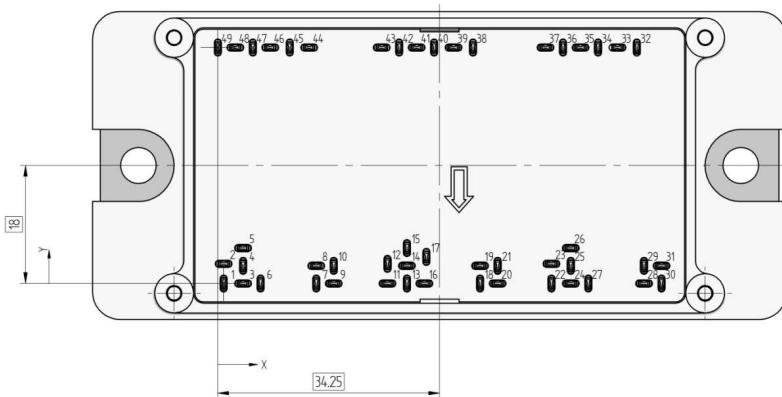
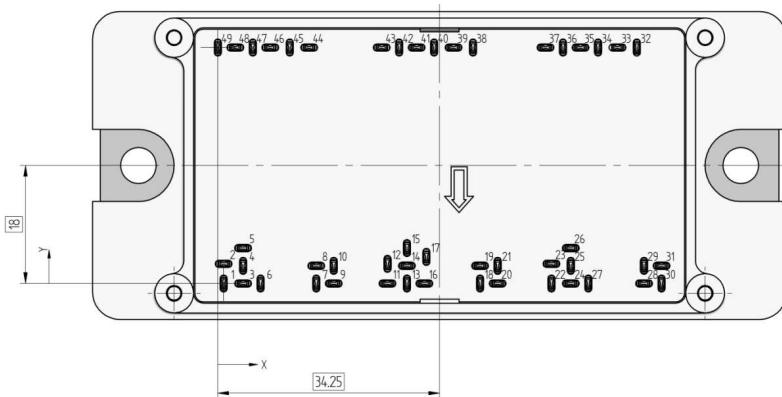
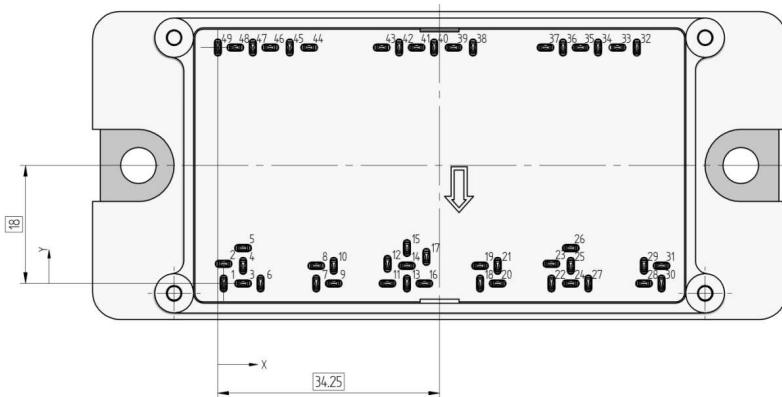
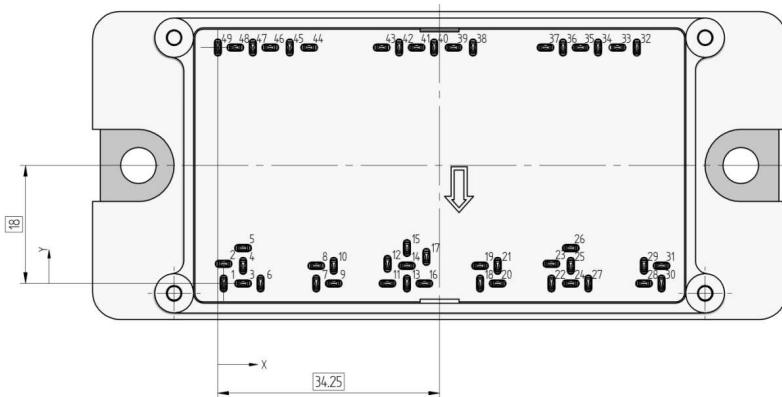
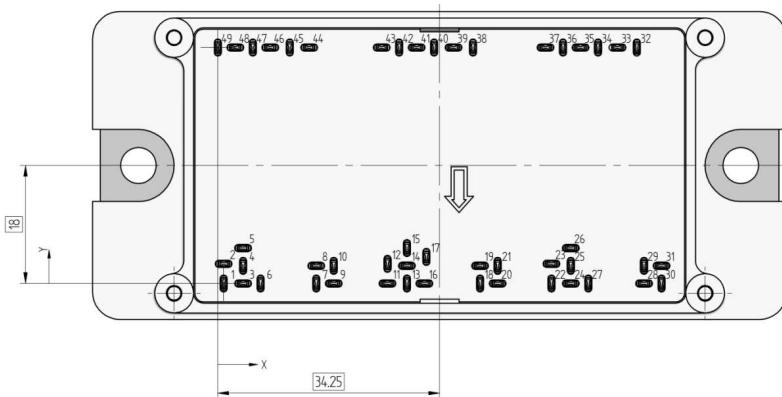
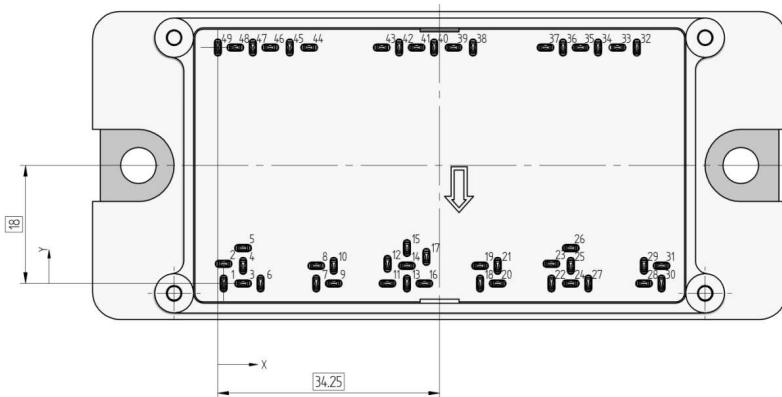
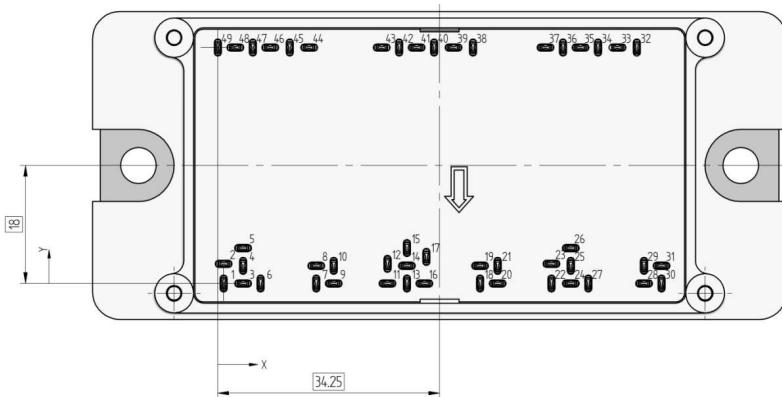
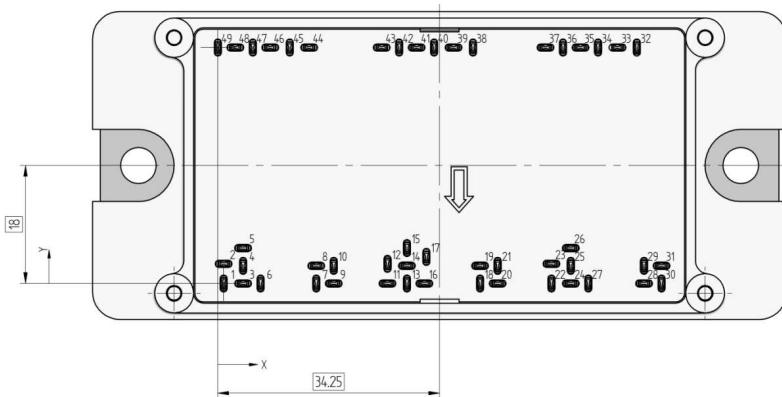
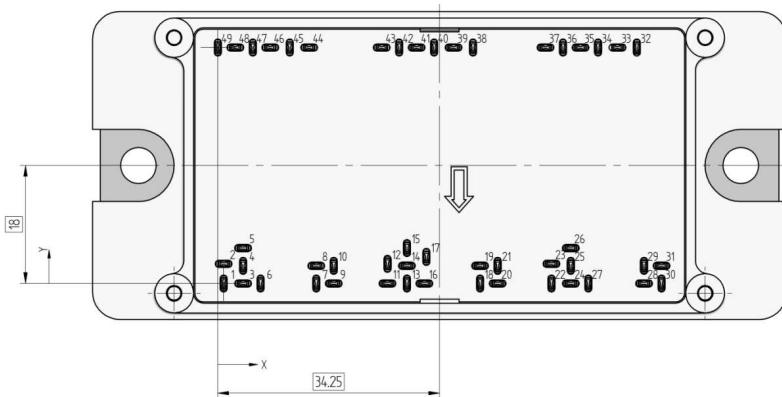
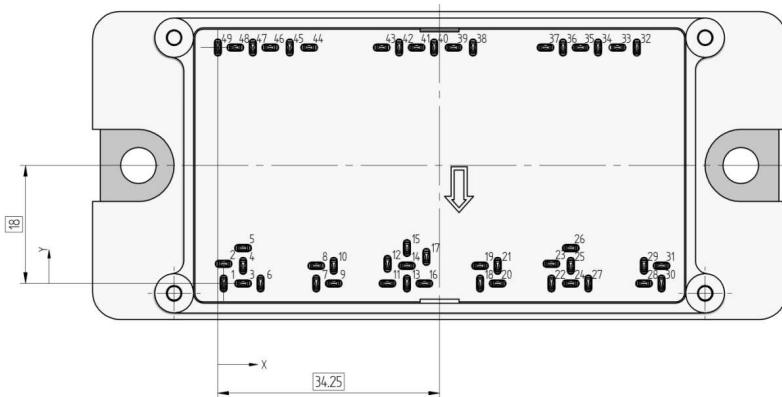
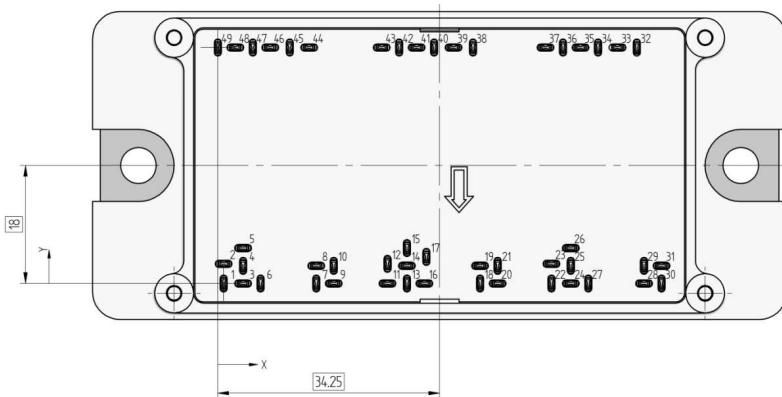
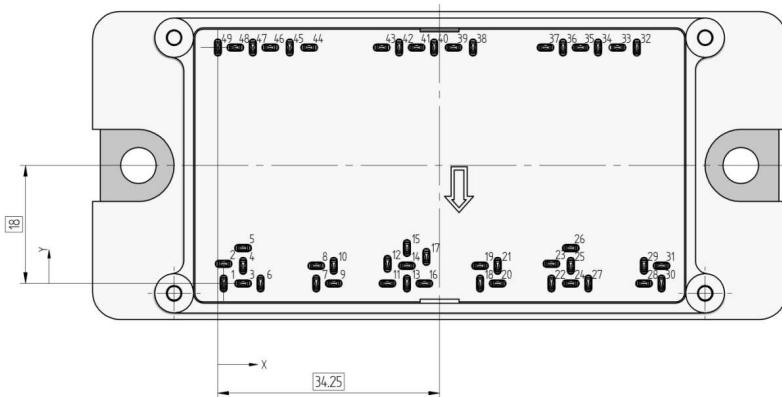
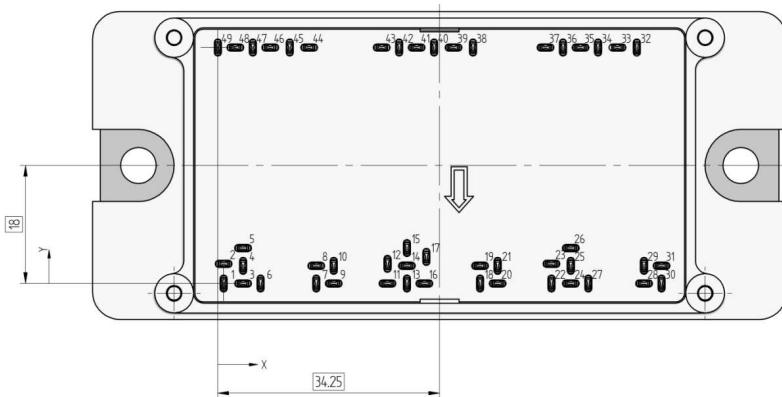
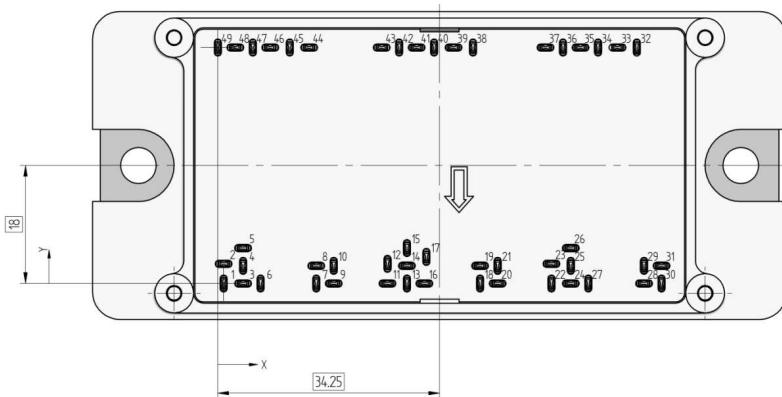
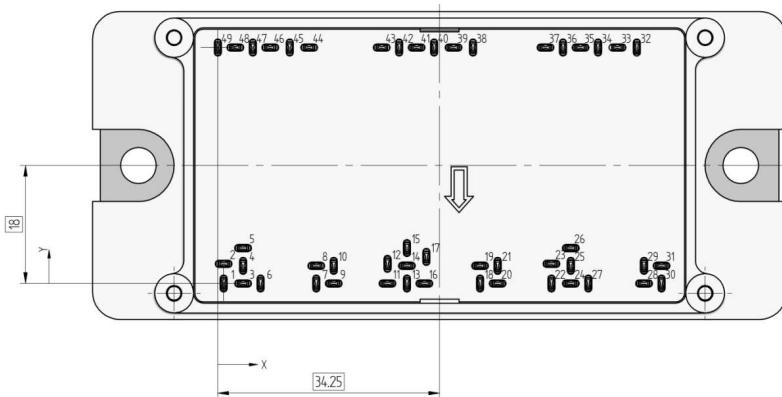
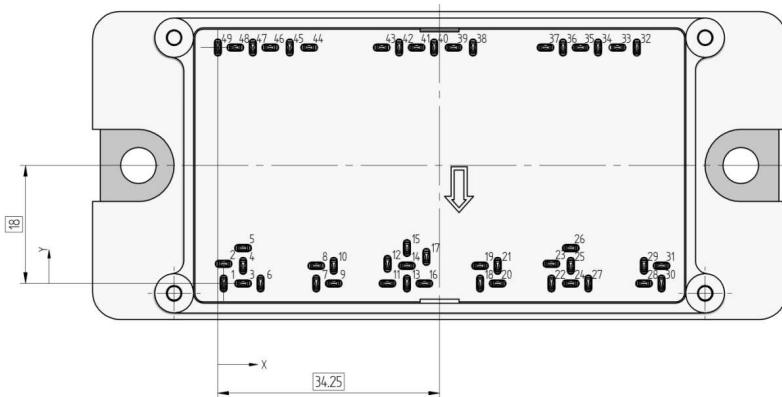
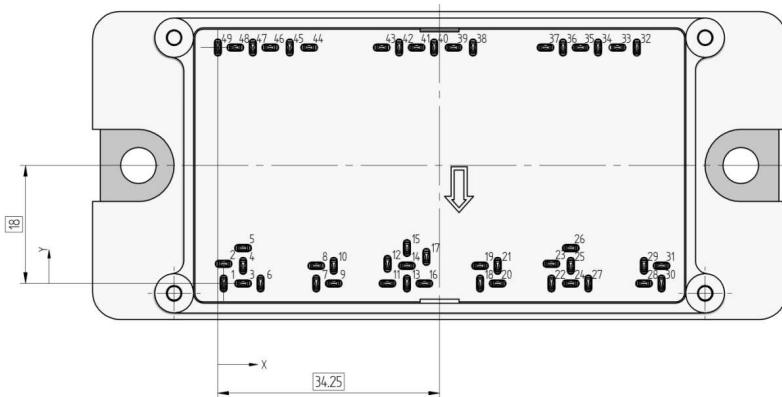
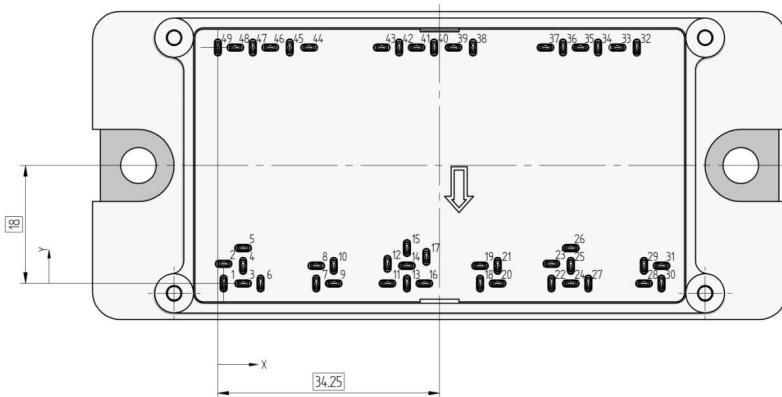
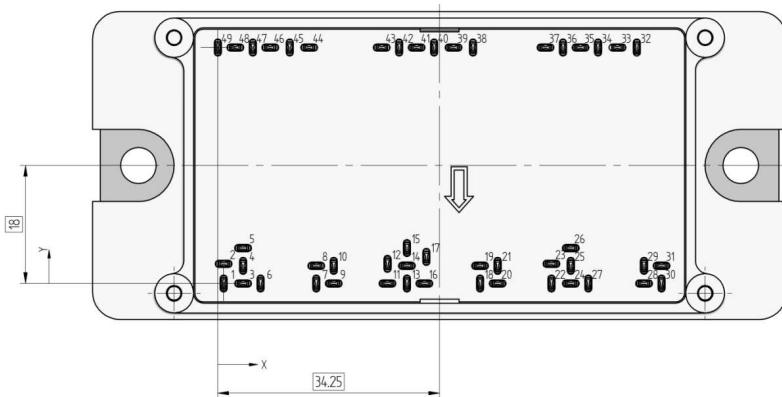
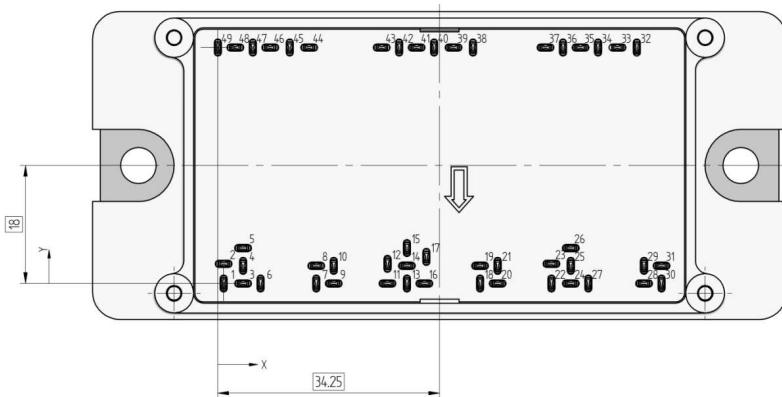
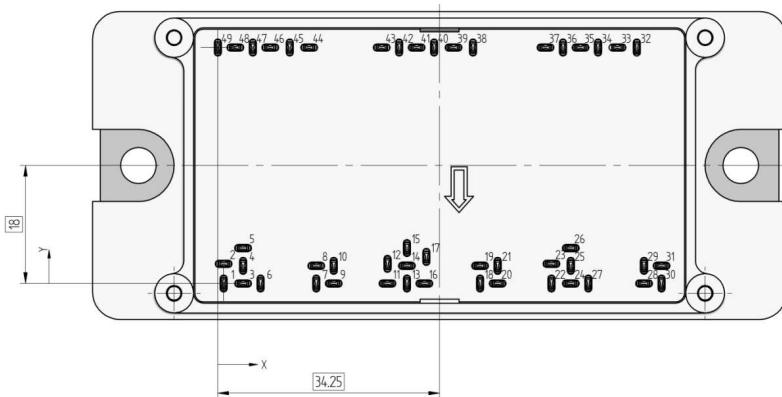
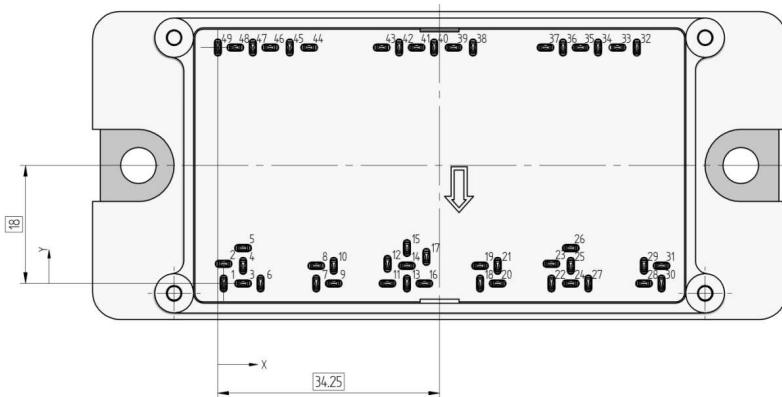
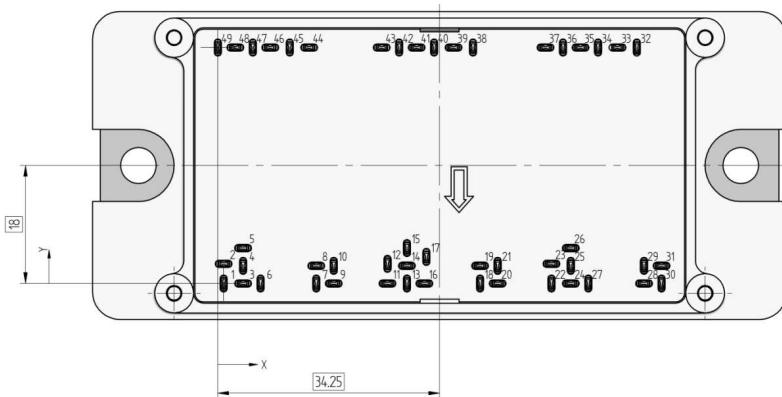
Inverter Switching Characteristics



**30-P2126PA050SC-L287F09Y**

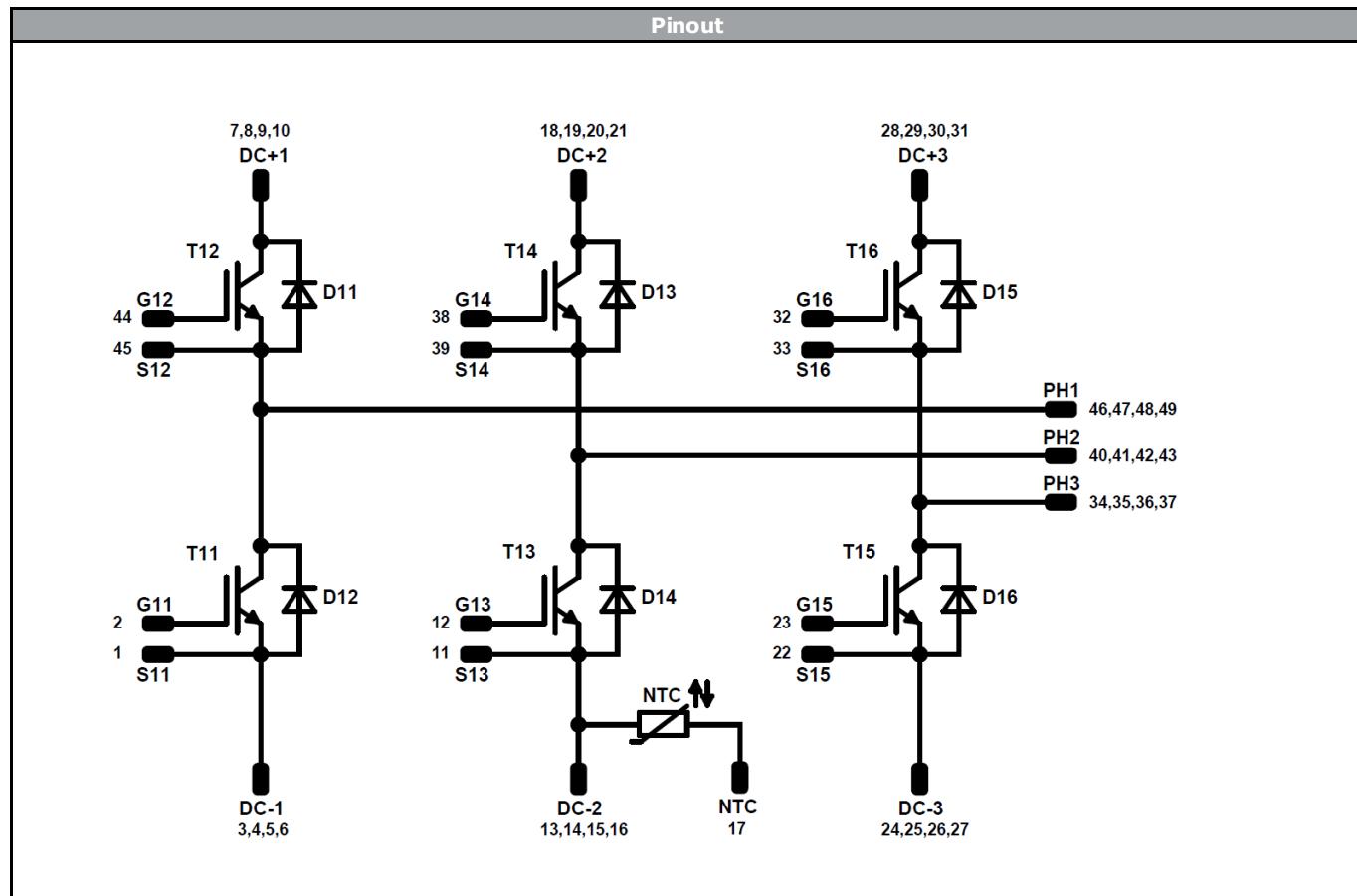
datasheet

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Ordering Code & Marking									
Version				Ordering Code					
without thermal paste 17 mm housing				30-P2126PA050SC-L287F09Y					
									
Text	Name	Date code	UL & VIN	Lot	Serial				
NN-NNNNNNNNNNNNN TTTTTTVVWWYY UL VIN LLLLL SSSS	N-NNNNNNNNNNNNNN-TTTTTTV	WWYY	UL VIN	LLLLL	SSSS				
Datamatrix	Type&Ver	Lot number	Serial	Date code					
	TTTTTTVV	LLLLL	SSSS	WWYY					
Outline									
Pin table [mm]		 Centerline of pinhead							
Pin	X	Y	Function	 Title					
1	0,9	0	S11	 Title					
2	0,9	3	G11	 Title					
3	3,9	0	DC-1	 Title					
4	3,9	2,7	DC-1	 Title					
5	3,9	5,4	DC-1	 Title					
6	6,6	0	DC-1	 Title					
7	15,2	0	DC+1	 Title					
8	15,2	2,7	DC+1	 Title					
9	17,9	0	DC+1	 Title					
10	17,9	2,7	DC+1	 Title					
11	26,2	0	S13	 Title					
12	26,2	3	G13	 Title					
13	29,2	0	DC-2	 Title					
14	29,2	2,7	DC-2	 Title					
15	29,2	5,4	DC-2	 Title					
16	31,9	0	DC-2	 Title					
17	32,2	4,05	NTC	 Title					
18	40,5	0	DC+2	 Title					
19	40,5	2,7	DC+2	 Title					
20	43,2	0	DC+2	 Title					
21	43,2	2,7	DC+2	 Title					
22	51,5	0	S15	 Title					
23	51,5	3	G15	 Title					
24	54,5	0	DC-3	 Title					
25	54,5	2,7	DC-3	 Title					
26	54,5	5,4	DC-3	 Title					
27	57,2	0	DC-3	 Title					
28	65,8	0	DC+3	 Title					
29	65,8	2,7	DC+3	 Title					
30	68,5	0	DC+3	 Title					
31	68,5	2,7	DC+3	 Title					
32	64,7	36	G16	 Title					
33	61,7	36	S16	 Title					
34	58,7	36	PH3	 Title					
35	56	36	PH3	 Title					
36	53,3	36	PH3	 Title					
37	50,6	36	PH3	 Title					
38	39,4	36	G14	 Title					
39	36,4	36	S14	 Title					
40	33,4	36	PH2	 Title					
41	30,7	36	PH2	 Title					
42	28	36	PH2	 Title					
43	25,3	36	PH2	 Title					
44	14,1	36	G12	 Title					
45	11,1	36	S12	 Title					
46	8,1	36	PH1	 Title					
47	5,4	36	PH1	 Title					
48	2,7	36	PH1	 Title					
49	0	36	PH1	 Title					



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11 , T12 , T13 , T14 , T15 , T16	IGBT	1200 V	50 A	Inverter Switch	
D11 , D12 , D13 , D14 , D15 , D16	FWD	1200 V	50 A	Inverter Diode	
Rt	Thermistor			Thermistor	



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datasheet

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Packaging instruction			
Standard packaging quantity (SPQ) 36	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for <i>flow</i> 2 packages see vincotech.com website.			

Package data			
Package data for <i>flow</i> 2 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
30-x2126PA050SC-L287F09x-D2-14	19 Apr. 2017		

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.